O \ P & C A

February 9, 2004

Fo: Communication of Patents
P.O.Box 1450
Alexandria, VA 22313-1450

Fr: George O. Saile, Reg. No. 19,572 28 Davis Avenue

Poughkeepsie, N.Y. 12603

Subject:

Serial No. 10/718,881 11/21/03

Yi-Lung Cheng et al.

A METHOD OF FORMING A BORDERLESS CONTACT OPENING FEATURING A COMPOSITE TRI-LAYER ETCH STOP MATERIAL

INFORMATION DISCLOSURE STATEMENT

Enclosed is Form PTO-1449, Information Disclosure Citation
In An Application.

The following Patents and/or Publications are submitted to comply with the duty of disclosure under CFR 1.97-1.99 and 37 CFR 1.56.

CERTIFICATE OF MAILING

I hereby certify that this correspondence is being deposited with the United States Postal Service as first class mail in an envelope addressed to: Commissioner for Patents, P.O. Box 1450, Alexandria, VA 22313-1450, on February , 2004.

Stephen B. Ackerman, Reg.# 37761

Signature/Date Sleph Backen 2/12/04

TSMC-03-431

The following four U.S. Patents describe methods of forming self-aligned contact and via openings using underlying etch stop layers:

- 1) U.S. Patent 5,972,722 to Visokay et al., "Adhesion Promoting Sacrificial Etch Stop Layer in Advanced Capacitor Structures."
- 2) U.S. Patent 5,596,230 to Hong, "Interconnection with Self-aligned Via Plug."
- 3) U.S. Patent 5,731,242 to Parat et al., "Self-aligned Contact Process in Semiconductor Fabrication."
- 4) U.S. Patent 6,080,674 to Wu et al., "Method for Forming Via Holes."

Sincerely,

Stephen B. Ackerman,

Reg. No. 37761

Doctor Humber (Openin) Afghemon Hu TSMC-03-431 718,88 INFORMA MON DISCLOSURE CITATION Applicant FEB 1 7 2004 NEAN APPLICATION FHing Date (Usin shouls il nocossary) U. S. PATENT DOCUMENTS REMINAR JULIM ALMO DATE A VALUMODIÁCY A DOCUMENT NUMBER DATE HULL CLASS BUBCULE 3 758 257 438 586 438 692 FOREIGN PATENT DOCUMENTS Translation DOCUMENT NUMBER OATE COUNTRY CLUSS SUBCLASS YES .00 OTHER DOCUMENTS (Including Author, Title, Date, Portliner Pages, Etc.) EXAMINER DATE CONCOERED

EXAMINER: Initial if citation considered, whether or not citation is in conformance with MPEP § 609; Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to the applicant.